

# DMTH6004LPSW 60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

#### **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Tc = +25°C (Note 5)
60)/	3.1mΩ @V <sub>GS</sub> = 10V	100A
60V	4.5mΩ @V <sub>GS</sub> = 4.5V	100A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

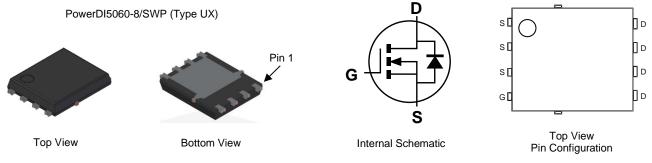
- Primary switches in isolated DC-DC
- Synchronous rectifiers
- Load switches

#### **Features**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production -. Ensures More Reliable and Robust End Application
- Low RDS(ON) Minimizes Power Losses •
- Low Qg Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. https://www.diodes.com/guality/product-definitions/
- An automotive-compliant part is available under separate datasheet (DMTH6004LPSWQ)

#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



### Ordering Information (Note 4)

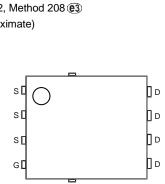
Orderable Part Number	Paakaga	Packing		
Orderable Part Number	Package	Qty.	Carrier	
DMTH6004LPSW-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

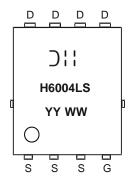
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Limited by package.





## **Marking Information**



D{} = Manufacturer's Marking H6004LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 24 = 2024) WW = Week (01 to 53)

## Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	60	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current (Note 6)	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	ID	22 16	А
Continuous Drain Current (Notes 5 & 7)	Tc = +25°C Tc = +100°C	ID	100 100	А
Maximum Continuous Body Diode Forward Current (Note 7)	•	ls	100	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	400	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		I <sub>SM</sub>	400	А
Avalanche Current, L = 0.2mH		las	40	А
Avalanche Energy, L = 0.2mH		Eas	160	mJ

## **Thermal Characteristic**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 6)	·	R <sub>0JA</sub>	47	°C/W
Total Power Dissipation (Note 7) $T_{C} = +25^{\circ}C$		PD	138	W
Thermal Resistance, Junction to Case (Note 7)		Rejc	0.9	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C

Notes: 5. Limited by package.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.7. Thermal resistance from junction to soldering point (on the exposed drain pad).



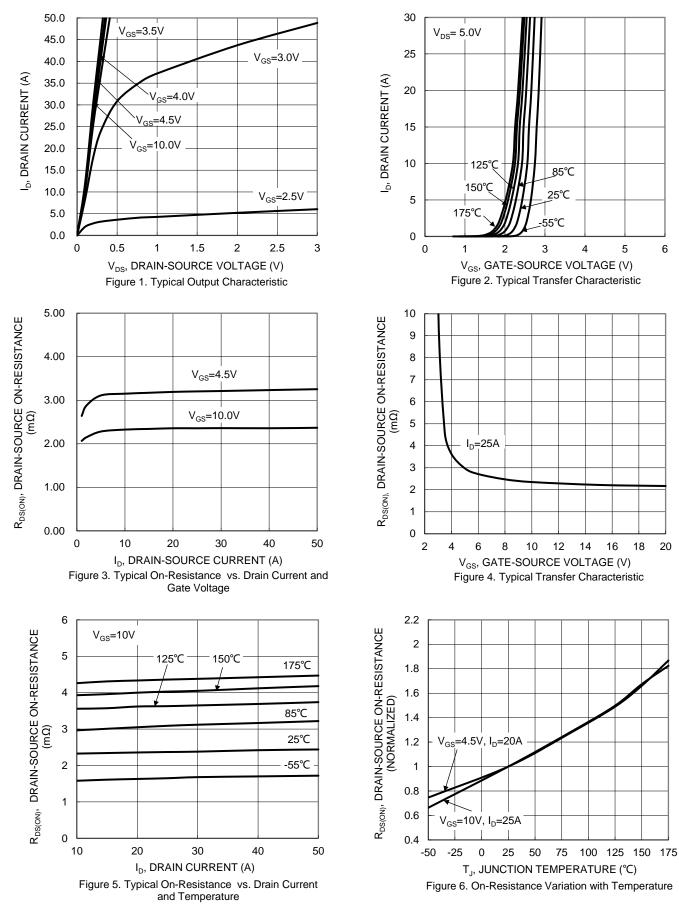
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

			_					
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 8)			1					
Drain-Source Breakdown Voltage	BVDSS	60	—	—	V	$V_{GS} = 0V, I_D = 1mA$		
Zero Gate Voltage Drain Current	IDSS	_		1	μA	$V_{DS} = 48V, V_{GS} = 0V$		
Gate-Source Leakage	IGSS		—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 8)	ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	VGS(TH)	1	—	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$		
Static Drain-Source On-Resistance	Descer		2.5	3.1	mΩ	VGS = 10V, ID = 25A		
Static Drain-Source On-Resistance	Rds(on)		3.3	4.5	mΩ	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 20A		
Diode Forward Voltage	V <sub>SD</sub>	_	_	1.3	V	$V_{GS} = 0V, I_{S} = 25A$		
DYNAMIC CHARACTERISTICS (Note 9)								
Input Capacitance	Ciss		5399	—		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz		
Output Capacitance	Coss		1306	—	pF			
Reverse Transfer Capacitance	Crss		92	—				
Gate Resistance	Rg	_	0.64	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		78.3	—		V <sub>DD</sub> = 30V, I <sub>D</sub> = 25A		
Total Gate Charge ( $V_{GS} = 4.5V$ )	Qg	_	38.5	_				
Gate-Source Charge	Q <sub>gs</sub>	_	10.2	_	nC			
Gate-Drain Charge	Qgd	_	20.4	_				
Turn-On Delay Time	t <sub>D(ON)</sub>	_	9.9	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 25A, R_G = 3.5\Omega$		
Turn-On Rise Time	tR	_	17.7	_	ns			
Turn-Off Delay Time	tD(OFF)	_	53.5	_				
Turn-Off Fall Time	tF	_	32.9	_				
Body Diode Reverse-Recovery Time	t <sub>RR</sub>	_	49.7	_	ns			
Body Diode Reverse-Recovery Charge	Q <sub>RR</sub>		78.9	<u> </u>	nC	I <sub>F</sub> = 25A, di/dt = 100A/μs		

Notes: 8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to production testing.

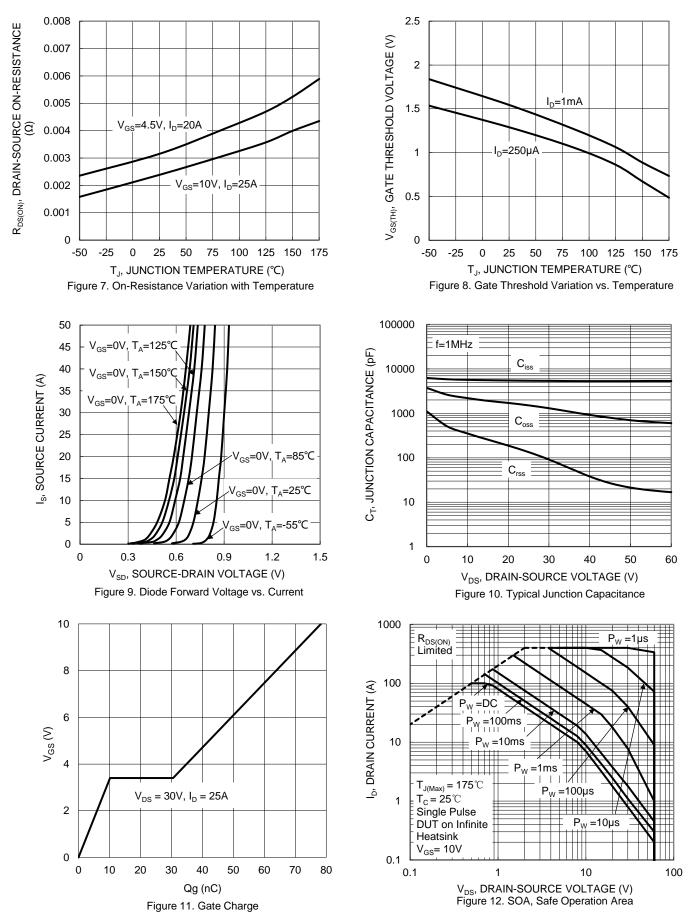


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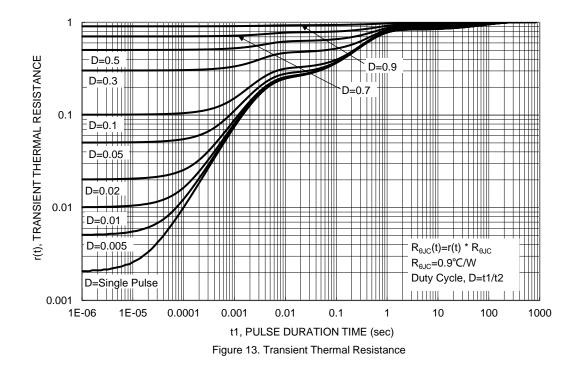


## DMTH6004LPSW



DMTH6004LPSW Document number: DS46918 Rev. 1 - 2



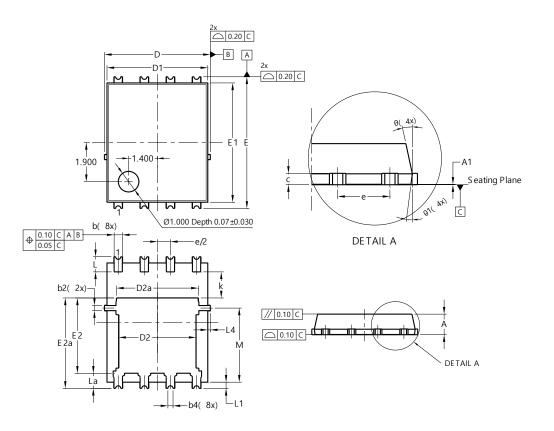




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8/SWP (Type UX)

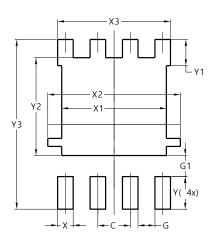


Po	PowerDI5060-8/SWP					
	(Type UX)					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0	0.05				
b	0.30	0.50	0.41			
b2	0.20	0.35	0.25			
b4	(	).25REF	-			
С	0.230	0.330	0.277			
D	5	.15 BS0	2			
D1	4.70	5.10	4.90			
D2	3.56	3.96	3.76			
D2a	3.78	3.78 4.18 3.98				
E	6	.40 BS0	5			
E1	5.60	6.00	5.80			
E2	3.46	3.86	3.66			
E2a	4.195	4.595	4.395			
е	1	.27BSC	)			
k	1.05					
L	0.635	0.835	0.735			
La	0.635	0.835	0.735			
L1	0.200	0.400	0.300			
L4	0.025	0.225	0.125			
Μ	3.205	4.005	3.605			
θ	10°	12°	11°			
θ1	6°	8°	7°			
All	All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	4.100		
X2	5.190		
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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